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L6452

Dual 13x16 Matrix Head Ink Jet Driver

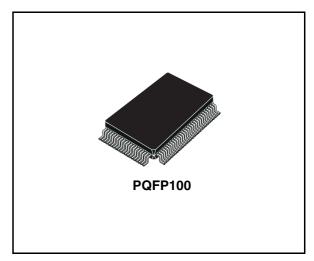
Features

- DRIVES TWO 13X16 MATRIX HEADS
- HEAD TEMPERATURE SENSING
- POWER UP SYSTEM
- ELECTRICAL NOZZLE CHECK
- 8 BIT A/D
- 5 BIT D/A
- ± 4KV ESD PROTECTED OUTPUTS

Description

L6452 is a device designed to drive two 13x16 matrix ink jet print heads in printer applications.

The output stage is able to source simultaneously 400 mA on each of the 16 power lines (columns) with a duty cycle of 33% in normal printing and 66% in head pre-heating. On the address lines (rows), the load is only capacitive (MOS FET driving capability). The driver can control two print heads, but only one is active at a time. The address scanning counter is included and can be disabled to allow a different scanning scheme.



In order to avoid output activation during the supply transient, an internal power-up system is implemented.

As supporting function, L6452 is capable of sensing the head silicon temperature and to electrically check each nozzle.

The device is also integrating a thermal protection.

Order codes

| Part number | Op. Temp range, $^\circ$ C | Package | Packing |
|-------------|----------------------------|---------|---------|
| E-L6452 | 0 to 70 | PQFP100 | Tray |
| L6452DIE8 | 0 to 70 | DIE | |

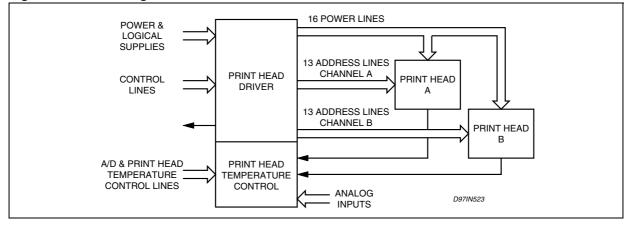
Contents

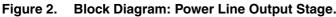
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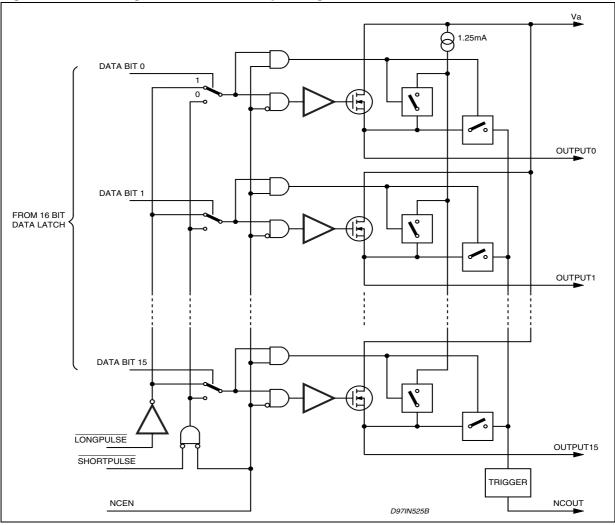


1 Block diagrams









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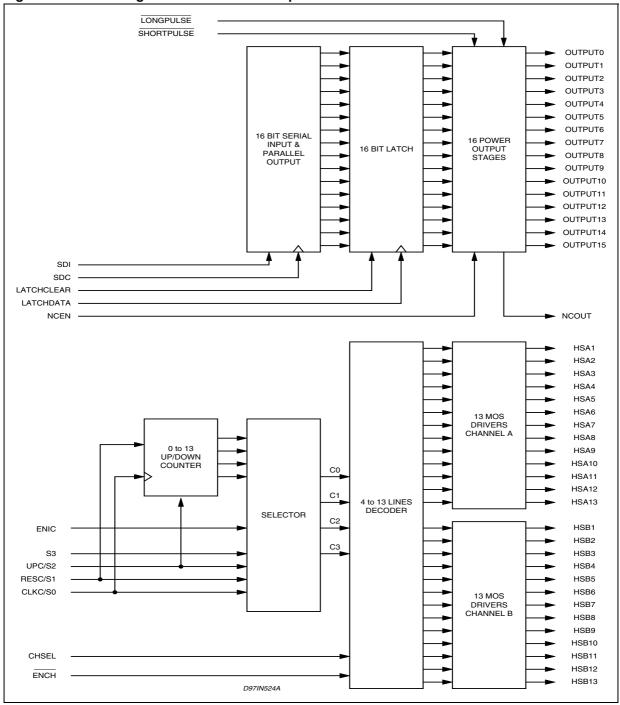
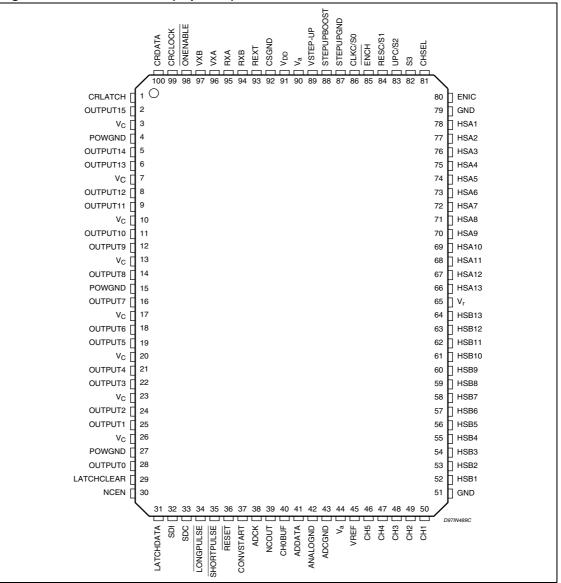


Figure 3. Block Diagram: Nozzle activation part



2 Pin description

Figure 4. Pin connection (Top view)



| Pin # | Name | Function |
|---|-----------|---|
| 1 | CRlatch | A rising edge transfer the information from CR shift register into the control register latching the data on the falling edge |
| 2, 5, 6, 8, 9, 11, 12, 14, 16, 18, 19, 21, 22, 24, 25, 28 | Output150 | High side DMOS outputs. To be active, ShortPulse and/or LongPulse and NcEn must have a low level |



| Table 1. Pin function - continued | | | | |
|---|------------|--|--|--|
| Pin # | Name | Function | | |
| 3, 7, 10, 13, 17, 20, 23, 26 | Vc | Outputs Power Supply | | |
| 4, 15, 27, 51, 79, 92 | GND | logic and power ground | | |
| 29 | LatchClear | A high level resets all bit in the latch | | |
| 30 | NcEn | A high level enables the internal current sources and disables all DMOS outputs. To be active, the internal current sources must have their corresponding bit set in the 16 bit latch and LongPulse must be set to low level. This function is called Nozzle Check Enable. | | |
| 31 | LatchData | A rising edge latches the 16 bit stored in the shift register in the 16 bit latch | | |
| 32 | SDI | Serial data input of the shift register | | |
| 33 | SDC | The data bit presented to the SDI pin is stored into the register on the rising edge of this pin | | |
| 34 | LongPulse | A low level activates all outputs having their corresponding bit in the 16 bit latch set (this pin has an internal pull-up resistor) | | |
| 35 | ShortPulse | A low level activates all outputs having their corresponding bit in the 16 bit latch reset (this pin has an internal pull-up resistor) | | |
| 36 | Reset | A low level disables all functions and clears all registers | | |
| 37 | ConvStart | A high level enables the A/D to start the new conversion | | |
| 38 | ADCK | A/D clock signal; the ADDATA signal are valid on the falling edge of this pin | | |
| 39 | NCOut | If NcEn is high this output provides a high level when the open load is detected on the output. If NcEn is low this output provides a high level when a short circuit is detected on HSA/B output | | |
| 40 | CH0buf | Analog output signal (CH0 buffered) | | |
| 41 | ADDATA | A/D serial data output | | |
| 42 | AnalogGND | Analog ground connection | | |
| 43 | ADCGND | Ground of internal ADC | | |
| 44, 90 | Va | Power supply | | |
| 45 | Vref | Reference voltage generator | | |
| 46 to 50 | CH5CH1 | A/D input signals | | |
| 52 to 64 | HSB1HSB13 | Head selector address output channel B | | |
| 65 | Vr | Head Select Power Supply | | |
| 66 to 78 | HSA13HSA1 | Head selector address output channel A | | |
| 80 | EnIC | Enable Internal Counter: A high level enables the counter and the internal decoder will activate of the HSx outputs according to the counter's outputs. Signal S0 becomes ClkC and S1 becomes ResC | | |

Table 1.Pin function - continued



| Pin # | Name | Function | | | |
|--------|-------------|--|--|--|--|
| 81 | ChSel | Channel Select: A low level enables channel A and a high level enables channel B | | | |
| 82 | S3 | Decoder input signals when EnIC is low | | | |
| 83 | UpC/S2 | UpCount/S2: A high level enables the internal counter to up counting. A low level enables down counting depending on EnIC value it becomes S2. | | | |
| 84 | ResC/S1 | Reset Count/S1: A low level resets the internal counter depending on EnIC value it becomes S1. | | | |
| 85 | EnCh | Enable Channel: A low level enables the selected channel (this input has an internal pull up resistor) | | | |
| 86 | ClkC/S0 | A high level clocks the internal counter depending on EnIC value it becomes S0. | | | |
| 87 | StepUpGND | Ground of step up block | | | |
| 88 | StepUpBoost | Boost voltage | | | |
| 89 | VstepUp | Driving voltage of power DMOS stage | | | |
| 91 | VDD | 5V logic supply | | | |
| 93 | Rext | An external resistor connected to ground fixes the internal current source value | | | |
| 94, 95 | RxB, RxA | Current source outputs | | | |
| 96, 97 | VxA, VxB | RxA, RxB voltage after an optional external filter | | | |
| 98 | OnEnable | A low level enables the current source generator according the \overline{A}/B and ON/ $\overline{O}FF$ control register bit | | | |
| 99 | CRclock | Data on pin CRdata are stored into the register on the rising edge of this pin | | | |
| 100 | CRdata | Control register serial data input | | | |

 Table 1.
 Pin function - continued



3 Electrical specifications

3.1 Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|----------------------|-------------------------------------|-------------------------------|------|
| V _c | Power line supply voltage | 14 | V |
| V _r | Address line supply voltage | 14 | V |
| Va | Analog supply voltage | 14 | V |
| V _{dd} | Logic supply voltage | 6 | V |
| V _{step_up} | Driving voltage of power DMOS stage | 28 | V |
| ESD | In accordance with IEC 1000-4-2 (1) | ±4 | kV |
| V _{in} | Logic input voltage range | -0.3 to V _{dd} + 0.3 | V |
| l _{out} | Output continuous current | 0.5 | А |
| Тj | Junction temperature | 150 | °C |
| T _{amb} | Operating temperature range | 0 to 70 | °C |
| T _{stg} | Storage temperature range | -55 to 150 | °C |

Table 2. Absolute maximum ratings

(1) All the pins connected to the pen passed ESD Contact Electrostatic Discharge @ ±4kV (150pF, 330Ohm source).

3.2 DC Electrical characteristics

Table 3. DC Electrical characteristics ($T_i = 25^{\circ}C$)

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Unit |
|-----------------|-------------------------------------|--|-------------|------|------|------|
| V _c | Power Line Supply voltage | (1) | 10.5 (2) | 11.5 | 12.5 | V |
| V _r | Address line supply voltage | (1) | 10.5 | 11.5 | 12.5 | V |
| Va | Analog supply voltage | (1) | 10.5 | 11.5 | 12.5 | V |
| V _{dd} | Logic supply voltage | | 4.5 | 5 | 5.5 | V |
| I _{cs} | V _c sleep supply current | | | | 1 | mA |
| I _{rs} | V _r sleep supply current | $\overline{\text{OnEnable}} = 1 \overline{\text{Reset}} = 0$ | | | 0.3 | mA |
| I _{as} | V _a sleep supply current | | | | 3 | mA |
| Ι _c | V _c supply current | | | | 1.5 | mA |
| I _r | V _r supply current | | | | 0.6 | mA |
| ا _a | V _a supply current | I _{Rext} = 3mA | | | 13 | mA |

| L | 64 | 4! | 52 |
|---|-----|----|----|
| | -0- | Τ. | _ |

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Unit |
|--------------------------|---|--|-----------------------|--------|--------------|--------|
| I _{dd} | V _{dd} supply current | sleep or normal condition | | | 5 | mA |
| V _{ref} | Reference Voltage | T _{amb} = 5 to 55°C | 4.85 | 5 | 5.15 | V |
| I _{refext} | Reference current (external) | | | | 7 | mA |
| I _{ccs} | Programmed constant current | $I_{ccs} = \frac{V_{ref}}{2R_{ext}} \cdot 4$ | | 12 | 13.5 | mA |
| $\Delta I_{ccs}/I_{ccs}$ | Constant current regulation | V_a =11V T_{amb} = 5 to 55°C | | 0.33 | | % |
| Vampout | Output voltage of integrated | | e ⁽³⁾ | | Va-1 | V |
| | amplifier | | | | | |
| V _{cm} | Operating input voltage at pins | V _{ref} = 5V g1=1.2 g2 = 3 | | | 7 | V |
| | Vxa and Vxb | | | | | |
| g1 | Amp. A1 Voltage gain | | 1.188 | 1.2 | 1.212 | |
| g2 | Amp.A2 Voltage gain | | 2.95 | 3.02 | 3.10 | |
| V _{step-up} | Driving Voltage of power DMOS | | | Vc +11 | | V |
| D CONVE | RTER | | | | | |
| V _{A/D in} | A/D input voltage | Selected Channel: CH1 to CH5 Selected Ch=CH0 | 0 e ⁽³⁾ | | Vref Vref | V V |
| I _{exch} | A/D input current | Input CH1 to CH5 selected or not | | | ±1 | μA |
| OFFSET VO | LTAGE GENERATION / DAC | I | | | | |
| Voffset | Offset Voltage | V _{ref} = 5V | 2.5+e (3) | | 7.34 | v |
| V _{step} | Voltage increment (1LSB) | Vref= 5V | | 156 | | mV |
| K _{dac} | Voffset/Vref | Any step N ≥ 4 | | | ±3 | % |
| D CONVE | RTER TIMINGS | | | | | |
| T _{cscks} | ConvStart set up time | | 200 | | | ns |
| T _{csckh} | ConvStart hold time | | 200 | | | ns |
| T _{ckout} | Falling edge of clock to data out valid delay | C _{load} ≤20pF | | | 200 | ns |
| T _{csz} | ConvStart falling edge to output in Hi-Z delay | | | | 200 | ns |
| F _{adck} | Clock frequency | | | | 250 | KHz |
| T _{cslow} | Conv. Start low level time | | 5.6 | | | μs |

Table 3. DC Electrical characteristics ($T_j = 25^{\circ}C$) - continued



| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Unit |
|--|---|------------------------------------|--------------------|------|--------------------|----------------------|
| T _{acqth} | Theoretical acquisition time | f _{adck} = 250 kHz | 32.4 | | | μs |
| T _{acqpr} | Real acquisition time | f _{adck} = 250 kHz | 36 | | | μs |
| DIGITAL IN | TERFACE INPUT | | | | | |
| V _{inp} | Schmitt Trigger positive-going Threshold | | | | 2/3V _{dd} | V |
| V _{inm} | Schmitt Trigger negative-going Threshold | | 1/3V _{dd} | | | V |
| Vhys | Schmitt Trigger Hysteresis | | 0.1 | 0.3 | 1 | V |
| lin | Input Current (Vin=0; V _{dd} =5) ⁽⁴⁾ | | 50 | 150 | 300 | μA |
| CR LATCH | TIMINGS | | | | 11 | |
| T _{ls} | Latch set up time | | 100 | | | ns |
| T _{lhigh} | Latch high time | | 100 | | | ns |
| T _{lconv} | Latch data valid to A/D input valid delay | Selected channel: CH1CH5 CH0 | 4 7 | | | μs μs |
| t _{store} | Latching data time | | 200 | | | ns |
| | | | 0.5 | | | |
| T _a | Set up time | | 35 | | | ns |
| Τ _b | Hold time | | 35 | | | ns |
| T _c | Serial clock low time | | 35 | | | ns |
| Τ _d | Serial clock high time | | 35 | | | |
| - | | | | | | ns |
| Т _е | Serial clock period | | 125 | | | |
| T _e T _f | Serial clock period Latch set up time | | 125 100 | | | ns |
| | · · · · · · · · · · · · · · · · · · · | | | | | ns ns |
| T _f | Latch set up time | | 100 | | | ns ns ns |
| T _f T _g | Latch set up time Latch data high time NcEn setup time with respect to LongPulse (or ShortPulse) | | 100 | | | ns ns ns ns |
| T _f T _g T _{set} | Latch set up time Latch data high time NcEn setup time with respect to LongPulse (or ShortPulse) Asserted NcEn hold time with respect to LongPulse (or ShortPulse) | | 100 100 160 | | | ns ns ns ns |

Table 3. DC Electrical characteristics ($T_j = 25^{\circ}C$) - continued



| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Unit |
|--------------------------|---|--|------|------|------|------|
| OUTPUTS E | LECTRICAL CHARACTERISTIC | S | 1 | 1 | 1 | |
| I _{out} | Output Current (outputs 015) | DC=33%; preheating DC=66% | | 400 | | mA |
| R _{ds(ON)} | On Resistance | T _j = 25°C | | | 1.3 | Ω |
| T _{pdr} | Power output Turn on Time | From 50% LongPulse to 90% power output rising edge Load = 30 Ohm in parallel with 1.5nF | | | 160 | ns |
| T _{pd} | Toff delay time | From 50% LongPulse to 90% power output falling edge Load = 30 Ohm in parallel with 1.5nF | | | 100 | ns |
| R _{pon} | Open Nozzle Check | | 0.5 | 1 | 2 | kΩ |
| HEAD ADD | RESS SELECTOR OUTPUT | | | | | |
| Т _h | UpC/S2, ResC/S1, ChSel, ClkC/S0 and EnIC set-up time with respect to EnCh | | 150 | | | ns |
| Τ _k | UpC/S2, ResC/S1, ChSel, ClkC/S0 and EnIC hold time with respect to EnCh | | 50 | | | ns |
| Тj | UpC/S2 with respect to hold time ClkC/S0 | | 200 | | | ns |
| Τ _i | UpC/S2 with respect to setup time ClkC/S0 | | 100 | | | ns |
| Τ _m | Enable input to active output delay time | | | | 100 | ns |
| T _n | Clock to active output delay time | | | | 150 | ns |
| To | Disable input to inactive output delay time | | | | 100 | ns |
| f _{clk-counter} | Counter Clock Frequency | | | | 1 | MHz |
| Clk _{dc} | Clock duty cycle | | 10 | | 90 | % |
| T _{on} | Address Turn on time | From 50% ClkC/S0 or selector | | | 325 | ns |
| T _{off} | Address Turn off time | signal to 90% of the address output variation Load: see <i>Figure</i> <i>11.</i> | | | 325 | ns |

Table 3. DC Electrical characteristics ($T_j = 25^{\circ}C$) - continued

(1) The three supply voltage are independent inside the specified value;

(2) The Min. value for V_c power line has been verified down to 4V in application lab.; nevertheless the parameters are guaranteed within spec limit of the above DC ELECTRICAL CHARACTERISTICS table.

(3) $e = 2 \cdot V_{step}$

(4) This applies to input pins having an internal pull-up (ENCH, LONGPULSE, SHORTPULSE)



3.3 Counter Truth Table

 $EnIC = 1 \\ UpC/S2 = 1 \\ ResC/S1 = 1$

| Clock Counter | C3 | C2 | C1 | C0 |
|---------------|----|----|----|----|
| 0 | 0 | 0 | 0 | 0 |
| | 0 | 0 | 0 | 1 |
| | 0 | 0 | 1 | 1 |
| | 0 | 0 | 1 | 0 |
| | 0 | 1 | 1 | 0 |
| | 0 | 1 | 1 | 1 |
| | 0 | 1 | 0 | 1 |
| | 0 | 1 | 0 | 0 |
| | 1 | 1 | 0 | 0 |
| | 1 | 1 | 0 | 1 |
| | 1 | 1 | 1 | 1 |
| | 1 | 1 | 1 | 0 |
| | 1 | 0 | 1 | 0 |
| | 1 | 0 | 0 | 0 |
| | 0 | 0 | 0 | 0 |

EnIC = 1UpC/S2 = 0ResC/S1 = 1

| Clock Counter | C3 | C2 | C1 | CO |
|---------------|----|----|----|----|
| 0 | 0 | 0 | 0 | 0 |
| | 1 | 0 | 0 | 0 |
| | 1 | 0 | 1 | 0 |
| | 1 | 1 | 1 | 0 |
| | 1 | 1 | 1 | 1 |
| | 1 | 1 | 0 | 1 |
| | 1 | 1 | 0 | 0 |
| | 0 | 1 | 0 | 0 |
| | 0 | 1 | 0 | 1 |
| | 0 | 1 | 1 | 1 |
| | 0 | 1 | 1 | 0 |
| | 0 | 0 | 1 | 0 |
| | 0 | 0 | 1 | 1 |
| | 0 | 0 | 0 | 1 |
| | 0 | 0 | 0 | 0 |



3.4 Decoder Truth Table

| OUTPUTS (HS) ACTIVE | C3* | C2* | C1* | C0* |
|------------------------|-----|-----|-----|-----|
| All inactive | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 1 |
| 2 | 0 | 0 | 1 | 1 |
| 3 | 0 | 0 | 1 | 0 |
| 4 | 0 | 1 | 1 | 0 |
| 5 | 0 | 1 | 1 | 1 |
| 6 | 0 | 1 | 0 | 1 |
| 7 | 0 | 1 | 0 | 0 |
| 8 | 1 | 1 | 0 | 0 |
| 9 | 1 | 1 | 0 | 1 |
| 10 | 1 | 1 | 1 | 1 |
| 11 | 1 | 1 | 1 | 0 |
| 12 | 1 | 0 | 1 | 0 |
| 13 | 1 | 0 | 0 | 0 |
| All inactive | 1 | 0 | 0 | 1 |
| All inactive | 1 | 0 | 1 | 1 |

* C3 = S3, C2 = S2, C1 = S1, C0 = S0, when EnIC = 0

This table is valid for both Channel A and Channel B and when \overline{EnCh} is set to low level.



4 Print Head Temperature Control Part

4.1 Introduction

For quality printing, it is necessary to know and control the temperature of the print head. Thus, the latter has a built - in aluminium resistor, whose value changes slightly with the temperature. The temperature determination is done by injecting a constant current in the resistor, and measuring the voltage drop across it. Since high - end printers have two heads, it must also be possible to switch quickly the measurement process from one to the other. The function is foreseen to be integrated into the head driver, and is described hereafter.

4.2 Print Head Block Diagram (*Figure 5.*)

At first we have a constant current source, which can be disabled by an external pin (OnEnable) or by a control register, described later. The value of the current can be programmed by an external resistor, and is given by:

$$I_{CCS} = \frac{V_{ref} \cdot 4}{2 \cdot R_{ext}}$$

This current is injected either into the resistor of the head A (Ralu. A) or B (Ralu. B), depending of the switch SW3. The resistors are grounded, and the voltage at their << hot >> side (Vx) is re-entered via the pins VxA and VxB. Using separate pins from RxA and RxB permits to be more flexible, and a filter can eventually be added as shown in the drawing.

The voltage Vx is amplified by A1 and A2, and then converted in a digital value. To be compatible with the input range of the A/D converter, it is necessary to subtract an offset voltage Voffset from Vx. Moreover, as the initial value of the aluminum resistor is very imprecise. Voffset must be adjustable; this is done by means of a 5 bit - D/A converter, giving 32 different values. Finally, the voltage at the input of the A/D converter is:

$$V_{CH0} = g1 \cdot g2 \cdot VX - g2 \times V_{OFFSET}$$

or

 $V_{CH0} = g1 \cdot g2 \cdot Ralu \cdot I_{CCS} - g2 \cdot V_{OFFSET};$

 $V_{OFFSET} = V_{REF}/2 + N \cdot V_{REF}/32 N = 0, 1, ...31$

The reference voltage generator (V_{REF}) is integrated, and used for the current source and both the A/D and D/A converters. In this way, the system performance is independent from the precision of V_{REF}; this one should, however, be stable. Vref is also available on pin #45, and can be used for low consumption purposes. (The external sinked current has to be a DC current).

The system is under control of a 10 bit register, CR. CR is accessed serially and has a transparent latch, which can be used or not (by trying the latch signal CR latch to V_{CC}).



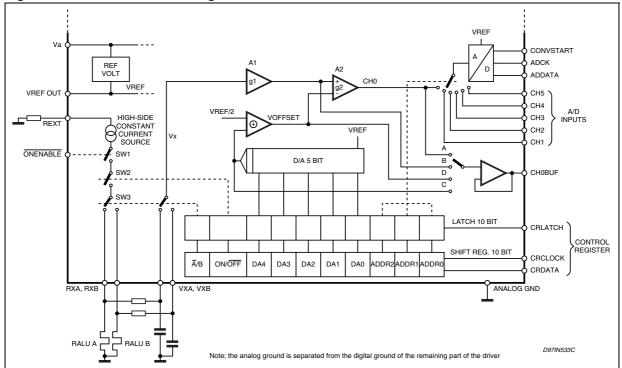
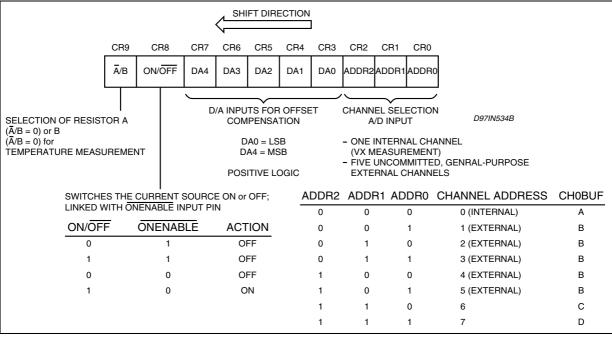


Figure 5. Print Head Block Diagram



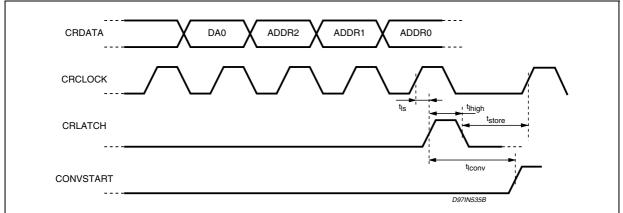






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Figure 7. CR Latch Timings





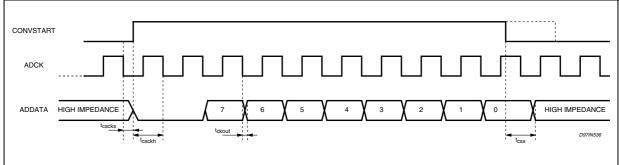
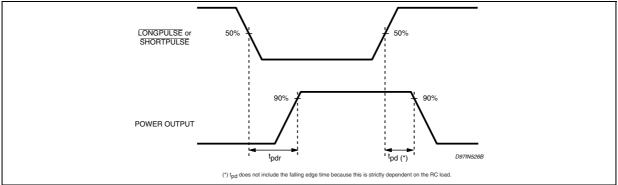


Figure 9. Power Output Timing





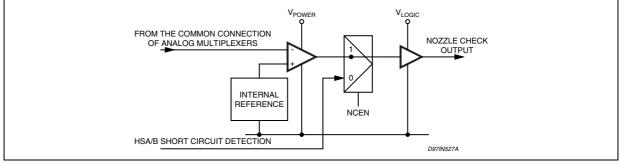


Figure 11. Address load reference

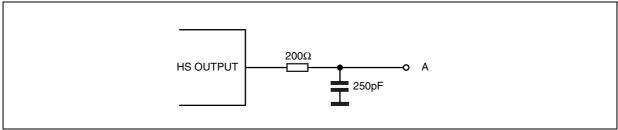


Figure 12. Mode Counter

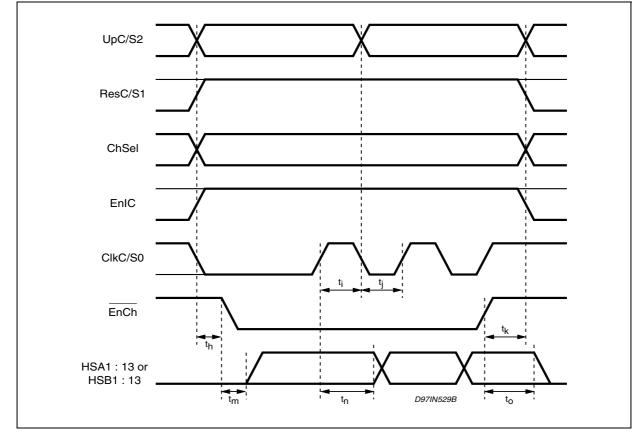




Figure 13. Mode Selelector

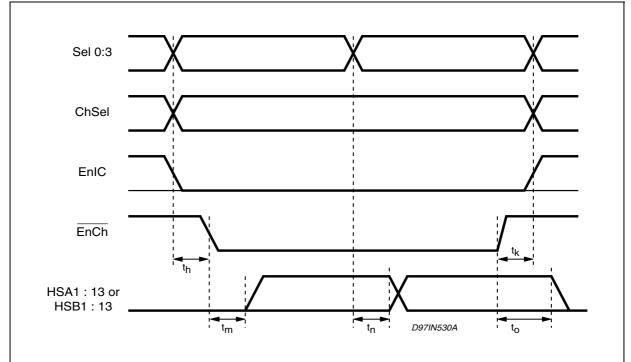
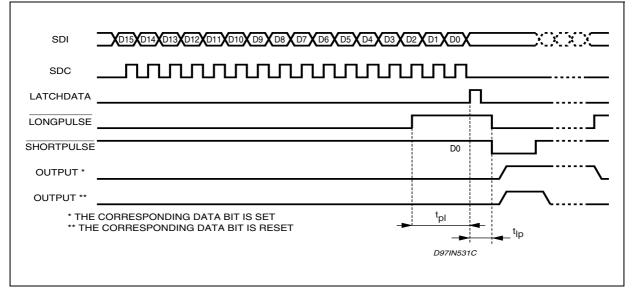
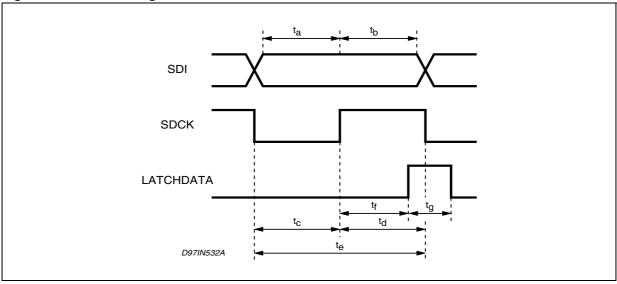


Figure 14. Sequence of Shift Register Data Loading











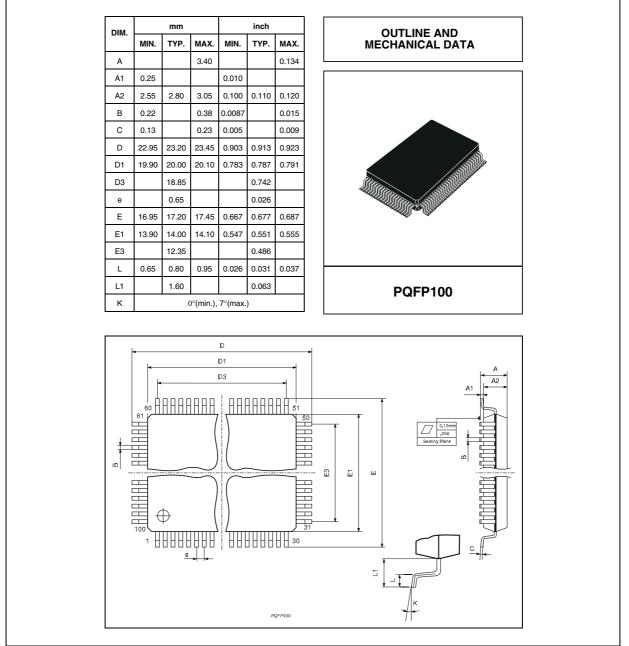
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5 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label.

ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Figure 16. PQFP100 Mechanical Data & Package Dimensions



L6452

6 Revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 15-Mar-1999 | 1 | Initial release. |
| 06-Feb-2006 | 2 | Modified Electrical Specification and any Time Diagrams. Modified pin and signal names through out the spec. Modified <i>Table 1</i> Pin function pins 83, 84 & 86. Added ESD parameter in the <i>Table 2</i> Absolute maximum ratings. Modified <i>Table 3</i> : T _{set} , T _{hold} and R _{pon} parameters. Modified <i>Figure 14</i> . |



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